

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- ◆ Planar MOS Schottky barrier diodes
- ◆ Low forward voltage drop
- ◆ low profile - typical body height 1.1 mm Moisture
- ◆ sensitivity: level 1, per J-STD-020
- ◆ High temperature soldering guaranteed: 260 °C/ 10 seconds
- ◆ RoHS Compliant
- ◆ Halogen-free according to IEC 61249-2-21 definition

Mechanical Data

Case : JEDEC TO-277 Molded plastic body

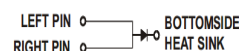
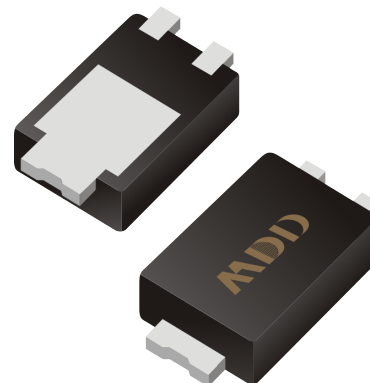
Case Material: Molding compound meets UL 94V-0 flammability rating

Terminals :Plated Leads Solderable per MIL-STD-202,Method 208

Polarity : Polarity symbol marking on body

Mounting Position : Any

Weight : 0.003 ounce, 0.092 grams

TO-277


Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

Parameter	SYMBOL	SL1045	UNIT
Marking Code		MDD SL1045	
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum DC blocking voltage	V_{DC}		
RMS Reverse voltage	V_{RMS}	32	V
Average Rectified Output Current	$I_{(O)}$	10	A
Non-Repetitive Peak Forward Surge8.3ms Single Half Sine-Wave Superimposed on rated load(JEDEC Method)	I_{FSM}	175	A
Typical Junction Capacitance (note1)	C_J	1200	pF

Electrical Characteristics Ta=25°C unless otherwise noted

Parameter	Test Conditions	Symbol	Value		Unit
			Typ	Max	
Forward Voltage Drop at 10A	TA=25°C TA=150°C	V_F	0.44	0.48	V
			--	0.42	
Peak reverse current at rated DC blocking voltage	TA=25°C TA=100°C	I_R	100	200	uA
			10	20	mA
Typical thermal resistance(note2)		$R_{\theta JA}$	65		°C/W
Operating junction storage temperature range		T_J	-55 to +150		°C
Storage temperaturerange		T_{STG}	-55 to +150		°C

note:1.Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

2.Polyimide PCB, 2oz. Copper. Cathode pad dimensions 18.8* 14.4*1.6mm. Anode pad dimensions 5.6 x 14.4*1.6mm.

Ratings And Characteristic Curves

FIG.1-TYPICAL FORWARD CURRENT
DERATING CURVE

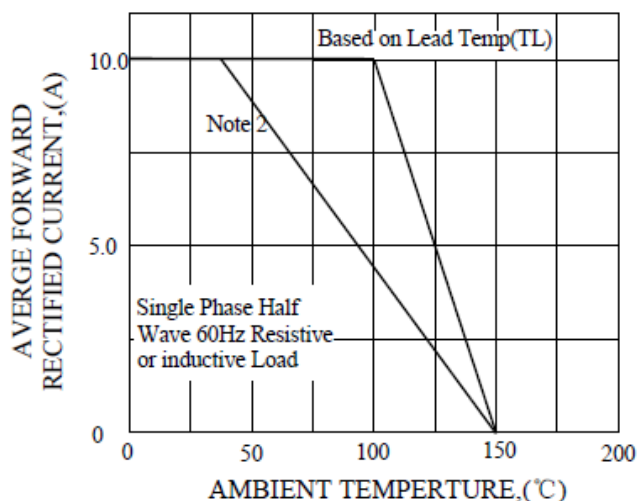


FIG.2-TYPICAL INSTANTANEOUS FORWARD
CHARACTERISTICS

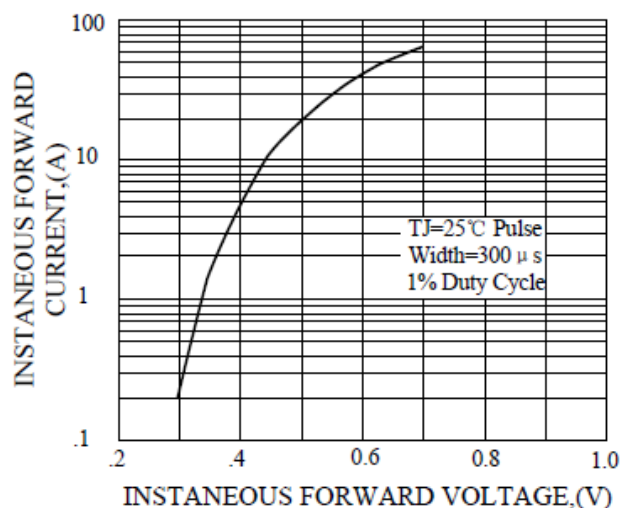


FIG.3-MAXIMUN NON-REPETITIVE
FORWARD SURGE CURRENT

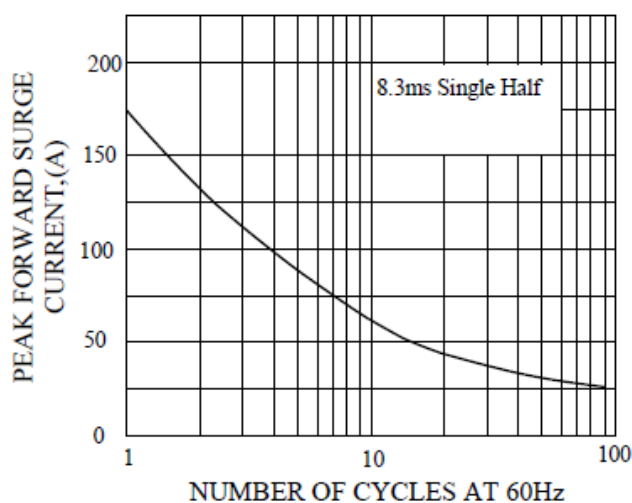
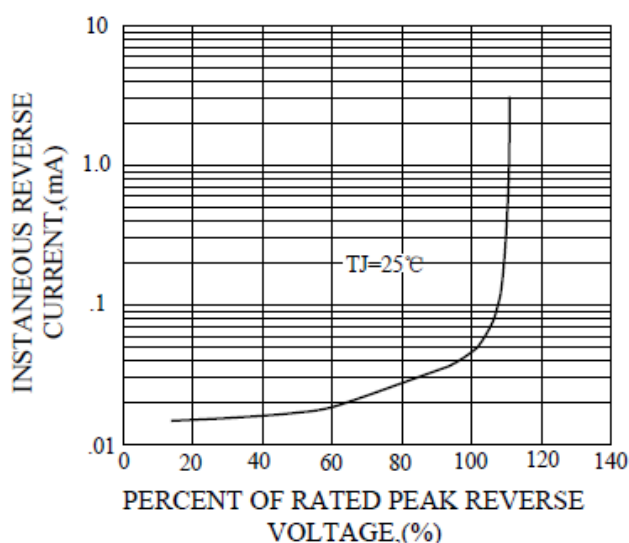
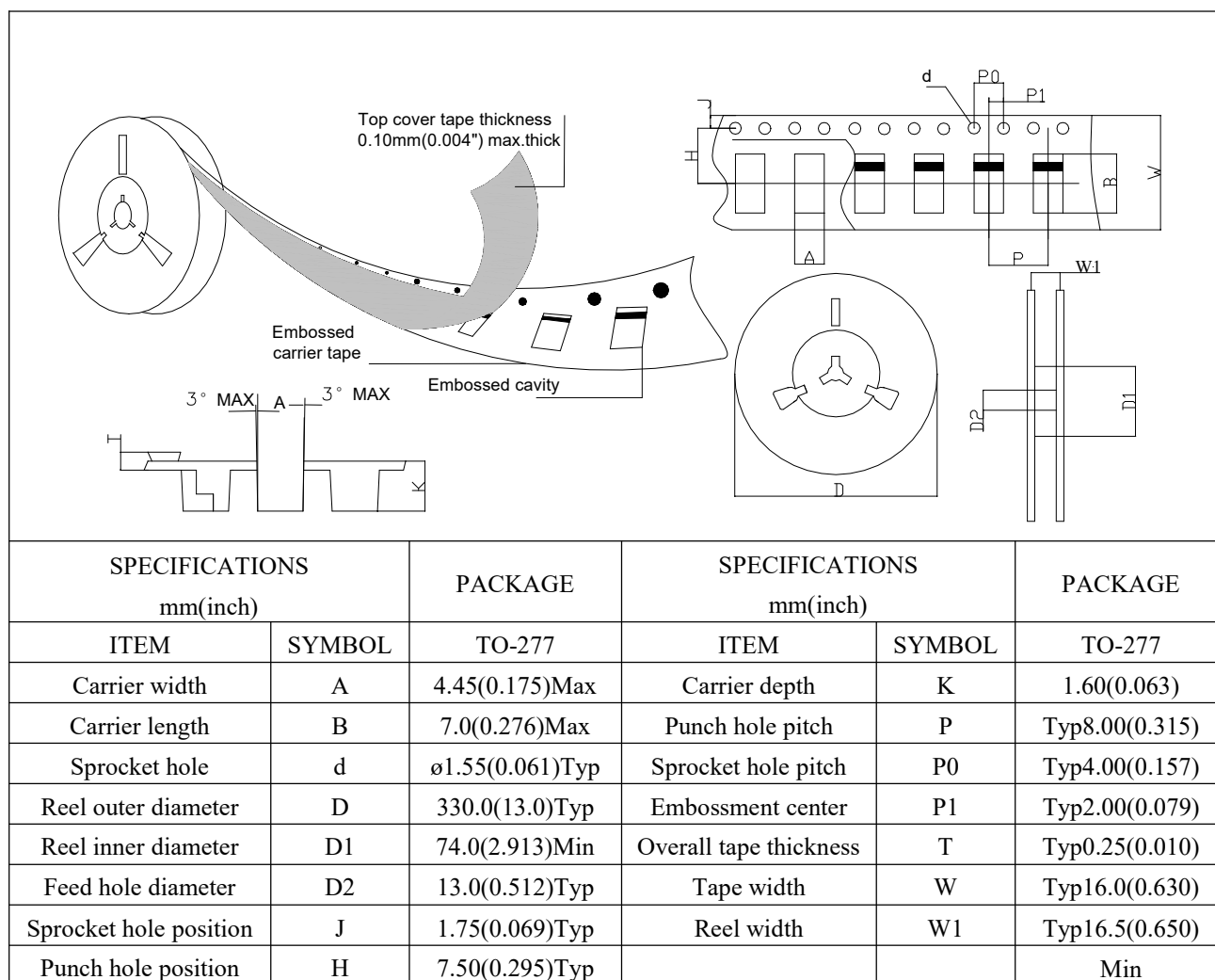


FIG.4-TYPICAL REVERSE
CHARACTERISTICS



The curve above is for reference only.

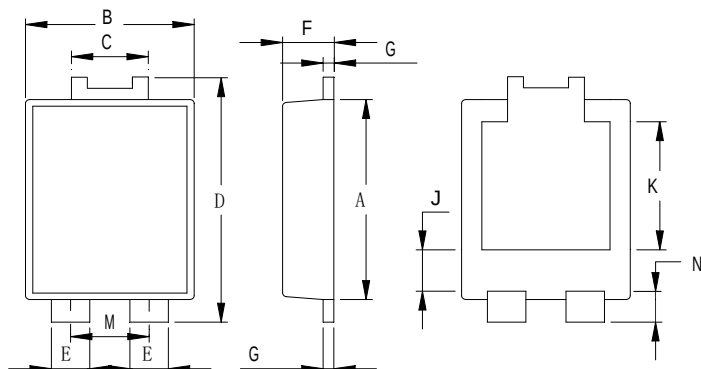
Packing information



Reel packing

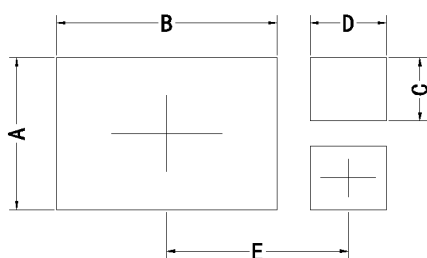
PACKAGE	REEL SIZE	REEL (pcs)	BOX (pcs)	INNER BOX (m/m)	CARTON SIZE (m/m)	CARTON (pcs)
TO-277	13"	3,000	6,000	338*338*38	350*350*330	36,000

TO-277 Outlitne Drawing



Symbol	imensions in Millimeters	
	Min	Max
A	5.2	5.8
B	3.8	4.3
C	1.7	1.9
D	6.4	6.6
E	0.8	1.0
F	1.0	1.3
G	0.2	0.45
J	1.1	1.5
K	2.4	4.0
M	1.65	1.95
N	0.7	1.3

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
A	3.60	0.142
B	5.35	0.211
C	1.50	0.059
D	1.85	0.073
E	4.30	0.169

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